## Excellent Integrated System Limited

Stocking Distributor

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Advanced Photonix, Inc. PDB-C505

For any questions, you can email us directly:
sales@integrated-circuit.com

## PHOTONIC DETECTORS INC.

## Silicon Photodiode, Photoconductive Fiber Optic Detector Type PDB-C505



## FEATURES

- High speed, 50 Mhz
- Low cost, PCB mount
- Includes connector
- Light tight package


## DESCRIPTION

The PDB-C505 is a high speed, PIN photodiode packaged in a low cost P.C.B mount plastic housing. Designed to interface with 1000 micron core plastic fiber for short haul fiber optic systems.Ideally matched with PDI-E521 IR orPDR-E526 red emitter. ABSOLUTE MAXIMUM RATING (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{BR}}$ | Reverse Voltage |  | 100 | V |
| $\mathrm{P}_{\mathrm{D}}$ | Total Power Dissipation |  | 200 | mW |
| $\mathrm{To}_{0}$ | Operating Temperature Range | -40 | +80 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{s}}$ | Soldering Temperature* |  | +260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 500 | mA |

*1/16 inch from case for 3 secs max

## APPLICATIONS

- High isolation interconnects
- Medical electronics
- Consumer electronics
- Micro processor

ELECTRO-OPTICAL CHARACTERISTICS (TA=25 ${ }^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | H = 1000 lux, 2850 K |  | 10 |  | $\mu \mathrm{A}$ |
| 1 D | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | . 20 | 20 | nA |
| Rsw | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | 500 | 1000 |  | $\mathrm{M} \Omega$ |
| TC Rsh | RSH Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -10 |  | \% / ${ }^{\circ} \mathrm{C}$ |
| CJ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}^{* *}$ |  | 5 |  | pF |
| $\lambda$ range | Spectral Application Range | Flooded D.C. | 400 |  | 1100 | nm |
| $\lambda p$ | Spectral Response - Peak | Spot Scan |  | 950 |  | nm |
| $V_{\text {bR }}$ | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 50 | 100 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{~V} @ 850 \mathrm{~nm}$ |  | $6 \times 10^{-15}$ |  | $\mathrm{W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | 6 |  | nS |

[^0]
[^0]:    Information inthistechnical data sheet is believed to be correctand reliable. However, no responsibility is assumedforpossibleinaccuracies or omission. Specifications are subjecttochangewithoutnotice. ${ }^{* *} \mathrm{f}=1 \mathrm{MHz}$
    [FORM NO. 100-PDB-C505 REV A]

